

Quantum Simulations and Machine Learning for Future Materials Technologies

Cem Sevik

**Computational Materials Modelling Lab, Department of Physics,
University of Antwerp**

Materials Modelling

2003 - High field transport phenomena in wide bandgap semiconductors.



Pentium 4 – 2GHz
512 MB RAM
Red Hat Linux

Materials Modelling

2008 -Carrier dynamics in silicon and germanium nanocrystals.



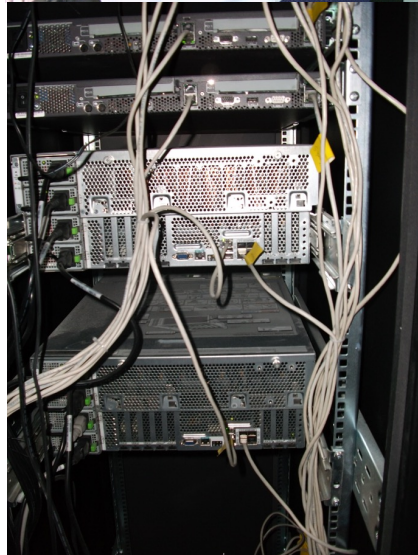
Pentium 4 – 3.4 GHz
1 GB RAM
GB Ethernet Connected
Red Hat Linux

Materials Modelling

2008 -Carrier dynamics in silicon and germanium nanocrystals.



5 Nodes
AMD Opteron 2 x dual-core
1 Node
AMD Opteron 4 x dual-core
8 GB
GB Ethernet Connected
Fedora



Materials Modelling

2012 – Electronic and thermal transport properties of 2D materials

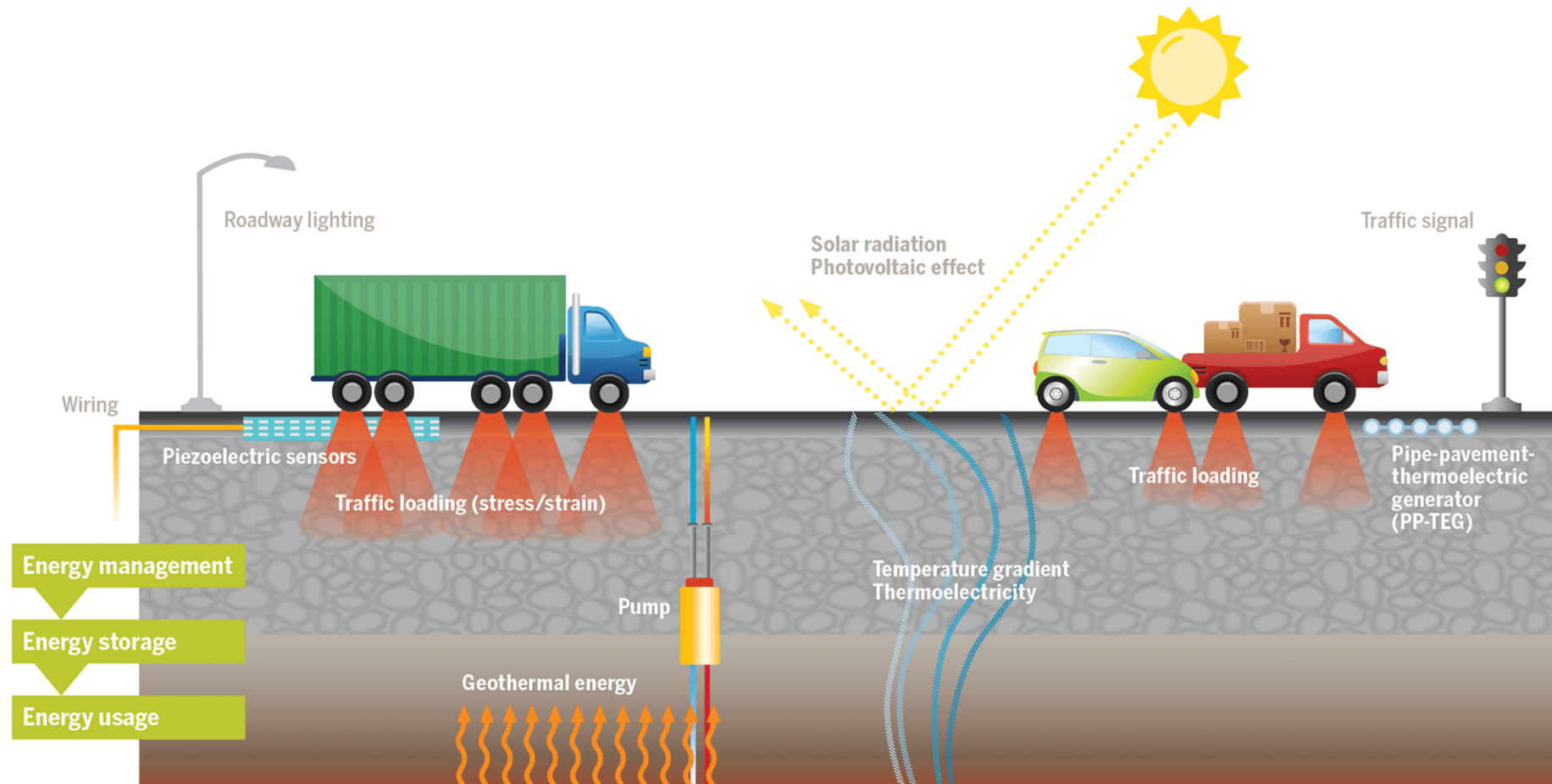


15 Nodes
2 Intel Xenon E5 8 cores
64 GB
InfiniBand connected
Rock Cluster

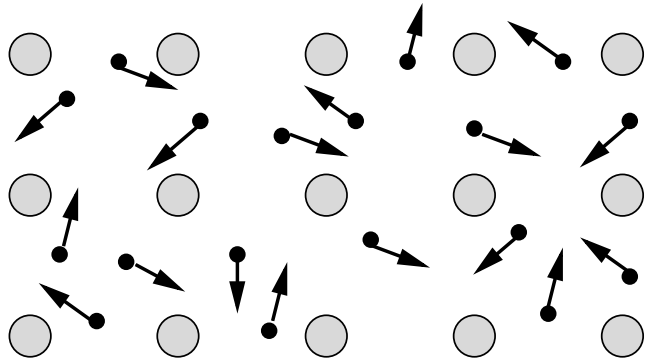
Materials Modelling



Why we need HPC power



Why we need HPC power



$$\hat{H} = \hat{H}_e + \hat{H}_n + \hat{H}_{n-e}$$

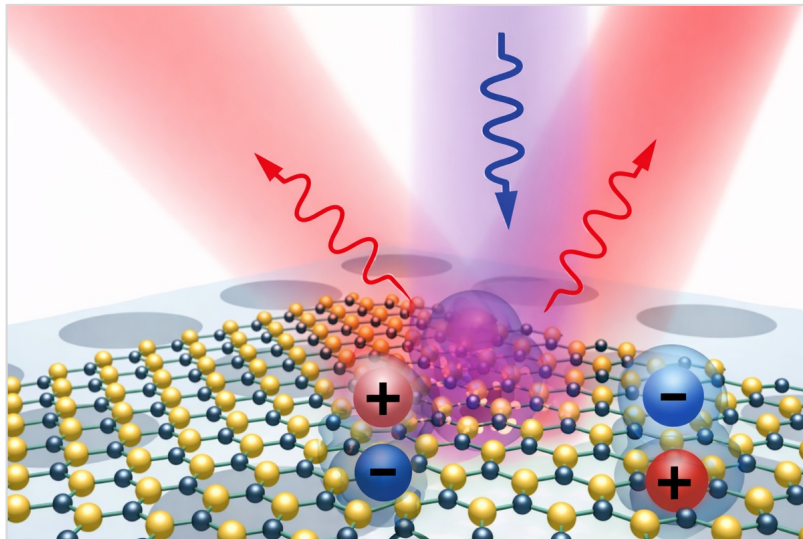
$$\hat{H}_e = \sum_i \frac{\hat{p}_i^2}{2m} + \frac{1}{2} \sum_{i \neq i'} \frac{e^2}{|\mathbf{r}_i - \mathbf{r}_{i'}|},$$

$$\hat{H}_n = \sum_j \frac{\hat{P}_j^2}{2M_j} + \frac{1}{2} \sum_{j \neq j'} \frac{Z_j Z_{j'} e^2}{|\mathbf{R}_j - \mathbf{R}_{j'}|},$$

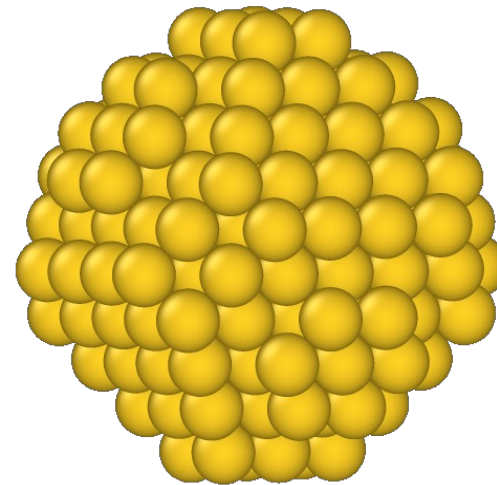
$$\hat{H}_{n-e} = - \sum_{i,j} \frac{Z_j e^2}{|\mathbf{r}_i - \mathbf{R}_j|},$$

Why we need HPC power

Many – Body Quantum
Simulations for Excitons

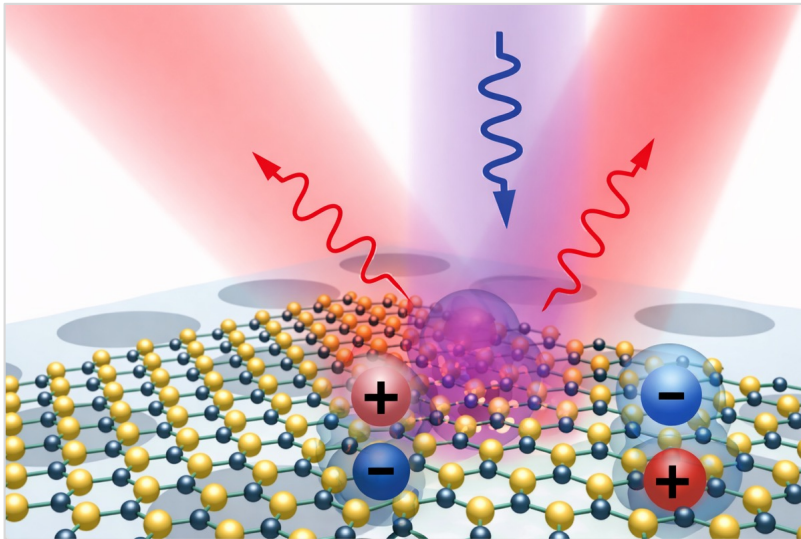


Machine Learning Interatomic
Potentials for Materials



Why we need HPC power

Many – Body Quantum Simulations for Excitons



VLAAMS
SUPERCOMPUTER
CENTRUM

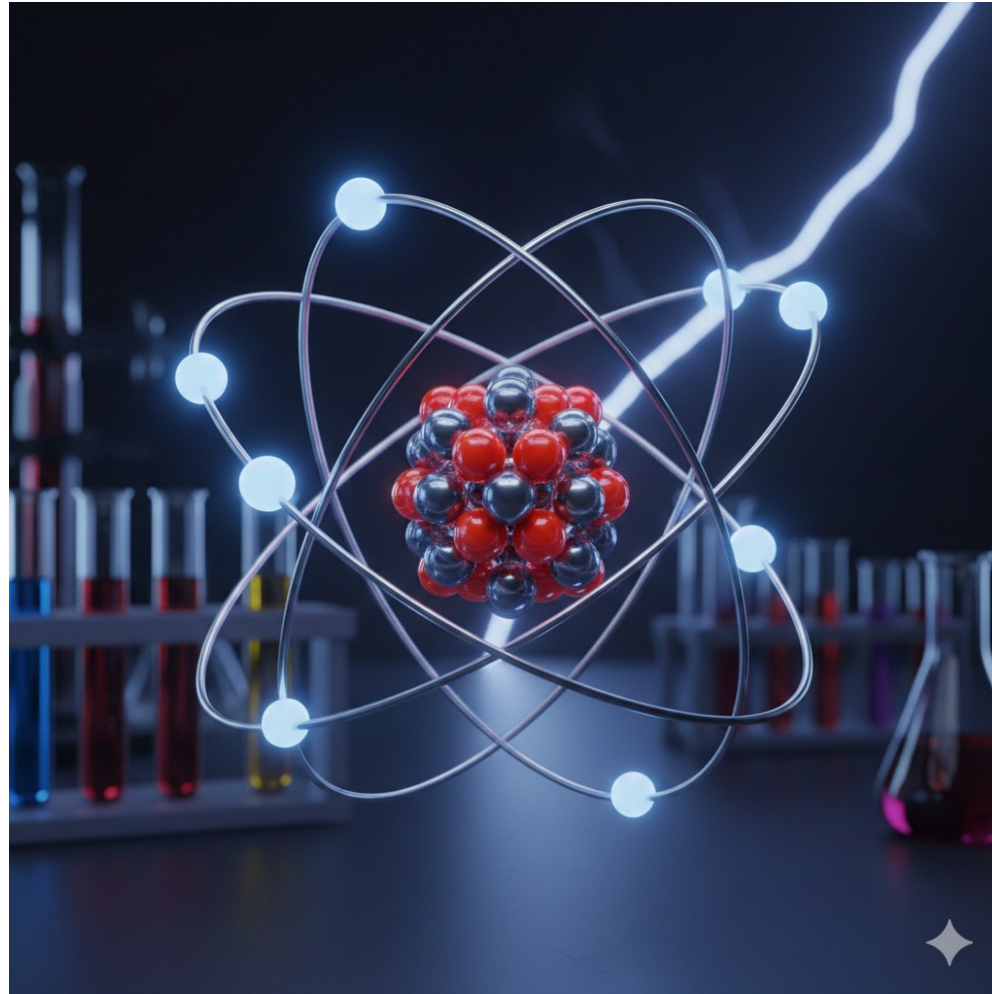


Vlaanderen
is supercomputing

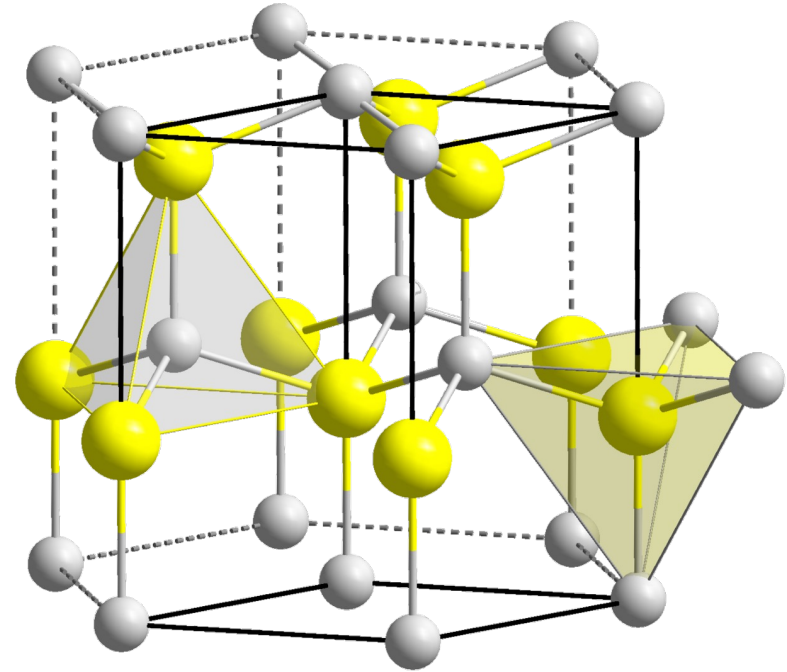
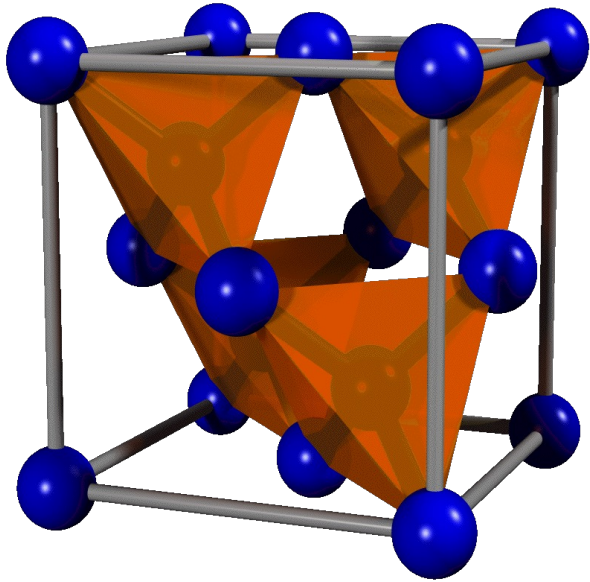


L U M I

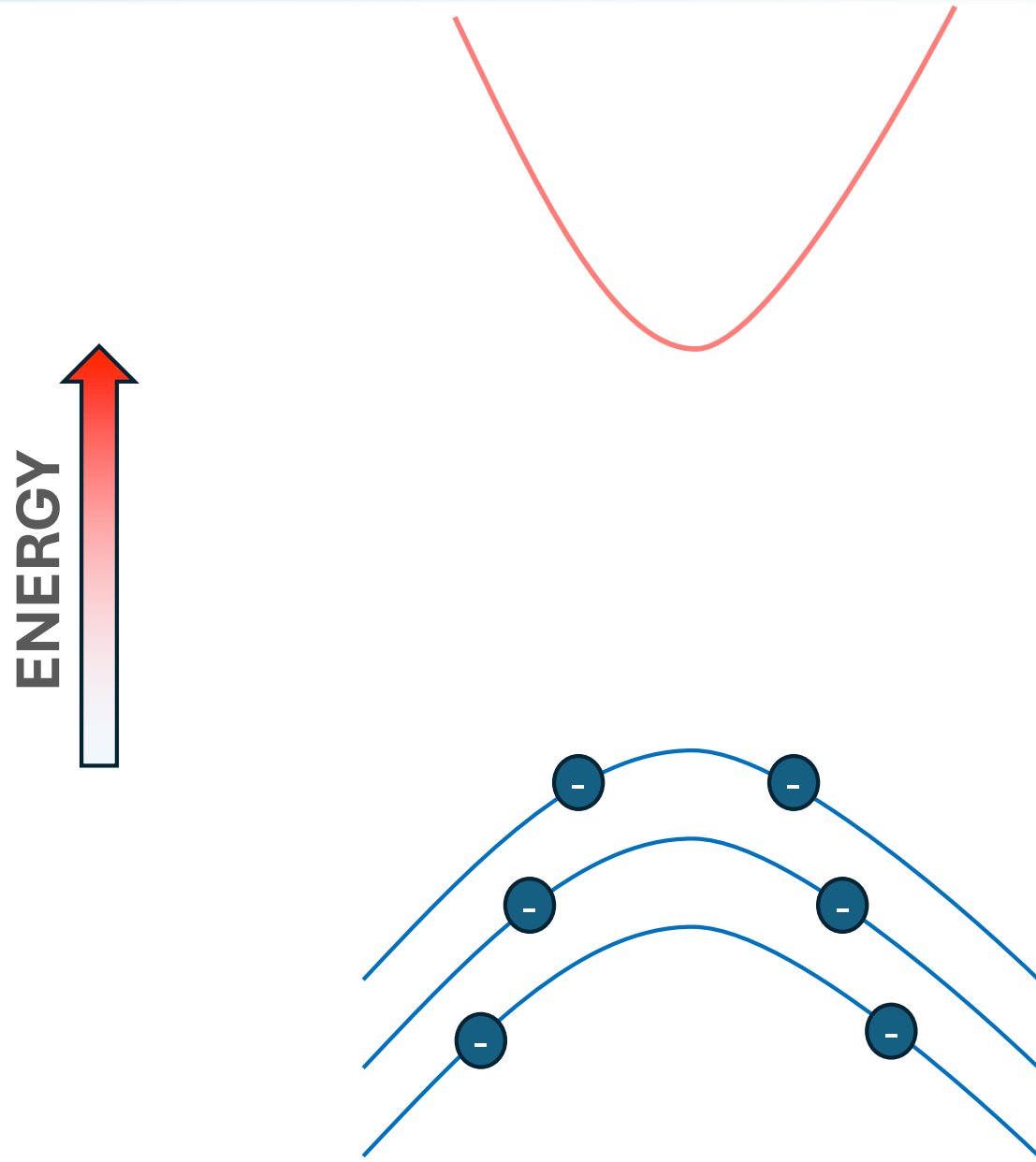
Why we need HPC power



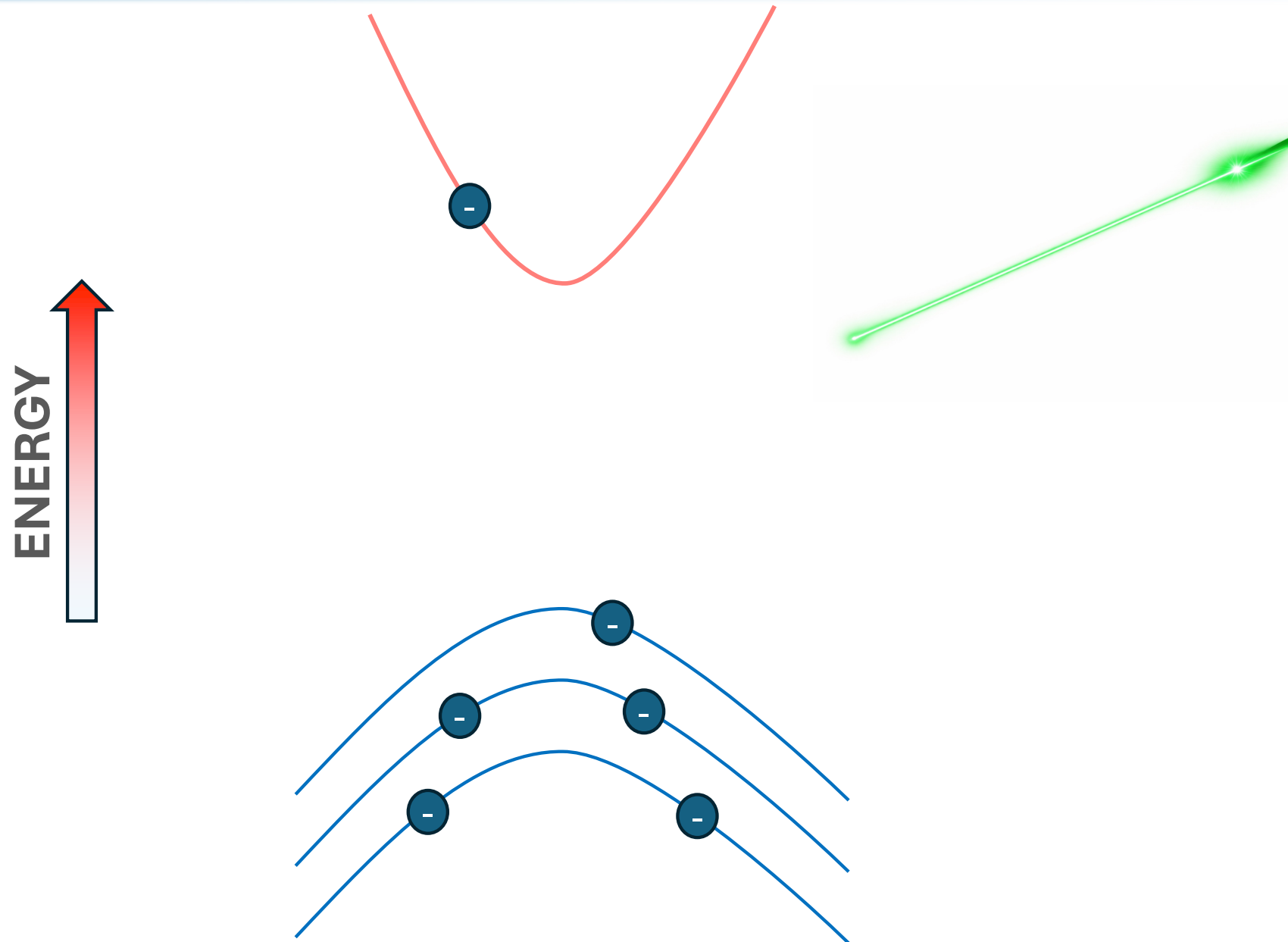
Why we need HPC power



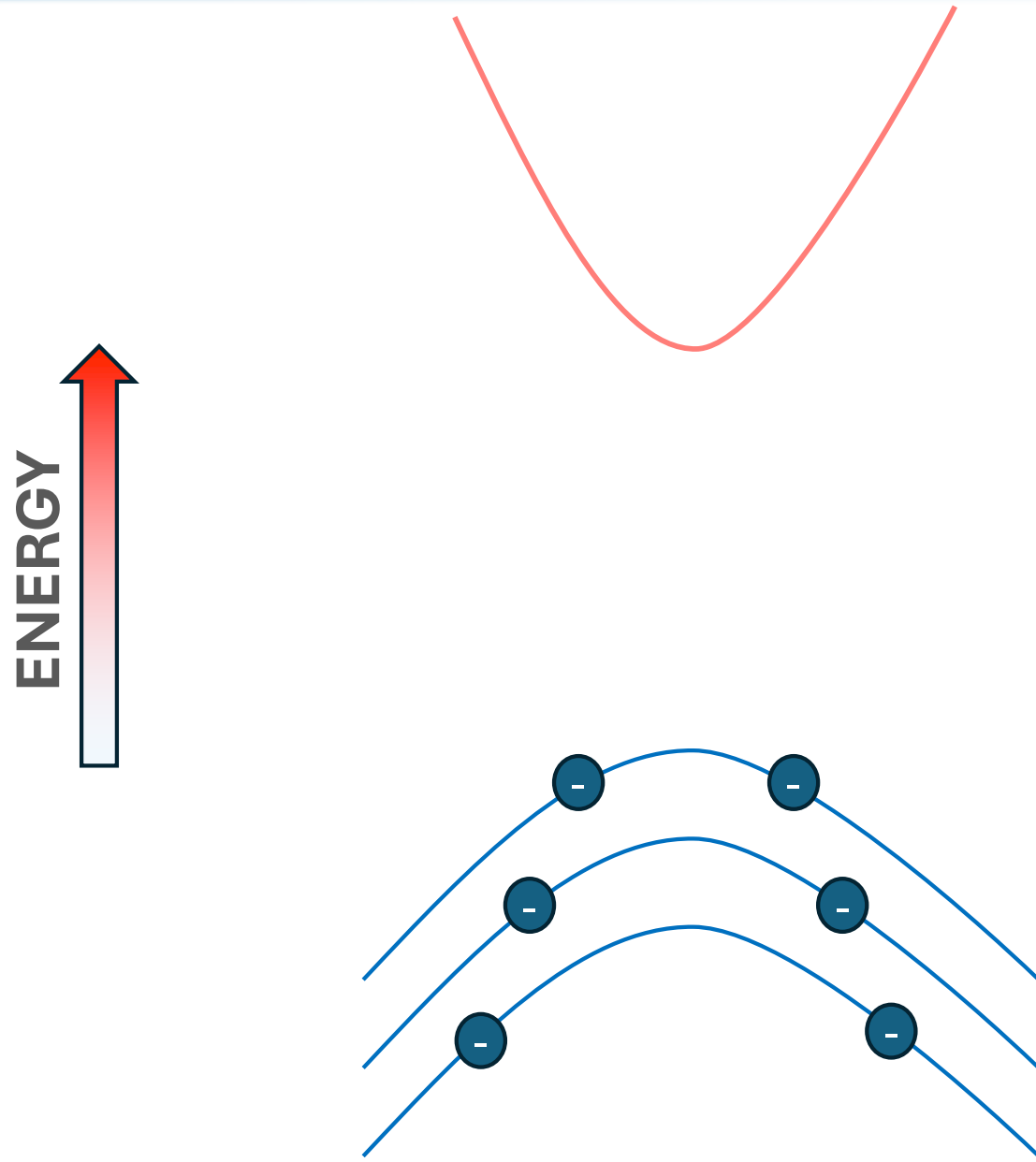
Why we need HPC power



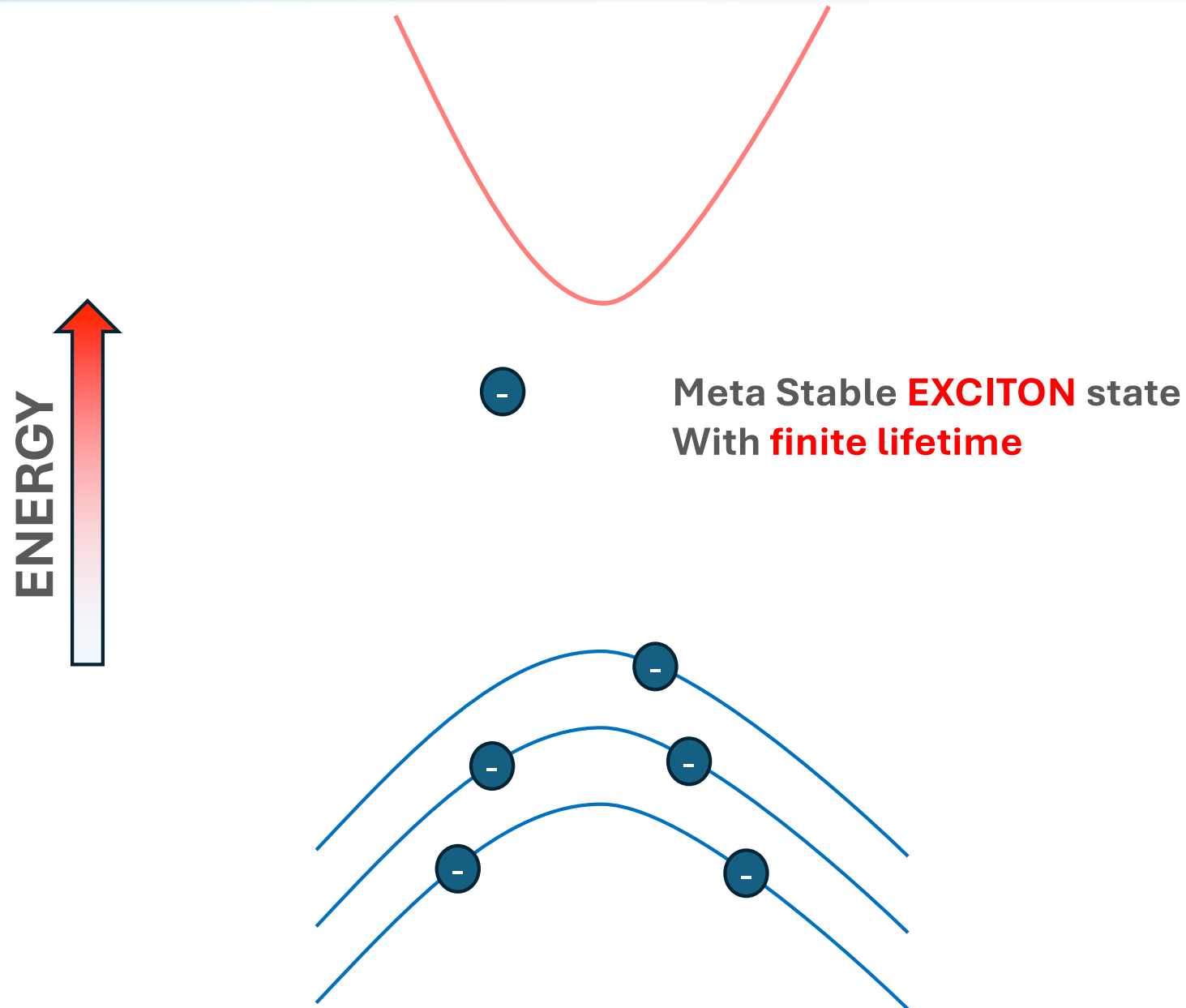
Why we need HPC power



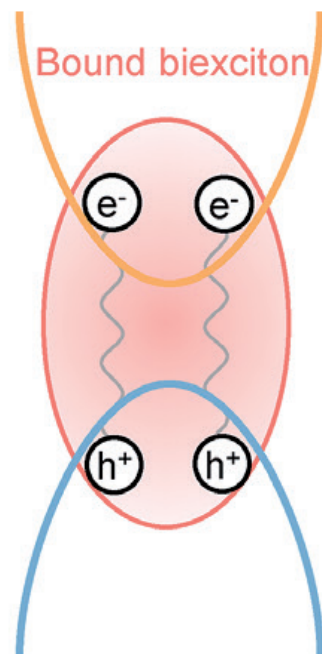
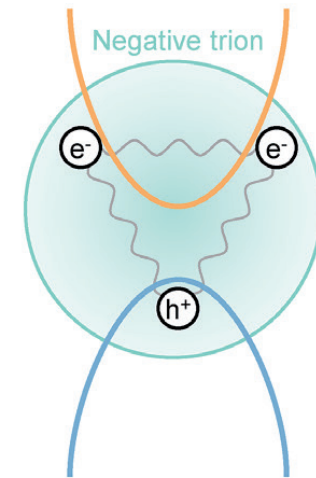
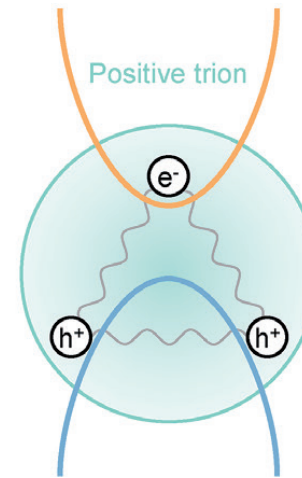
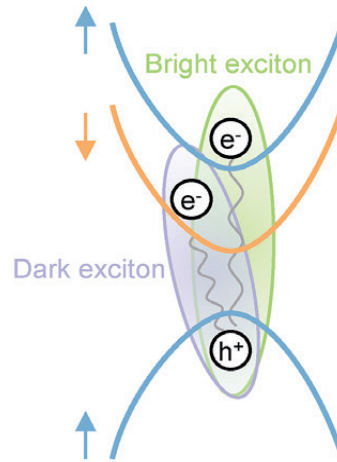
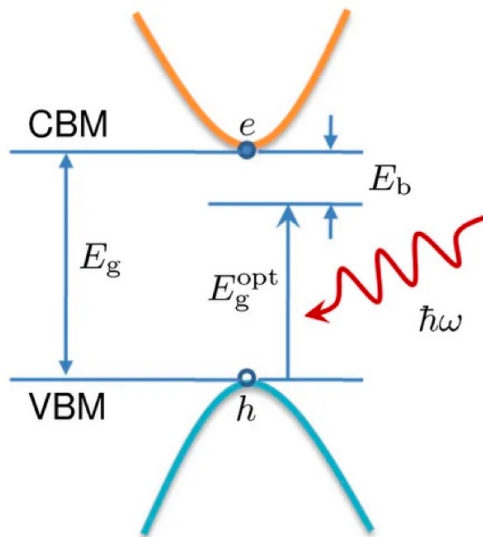
Why we need HPC power



Why we need HPC power



Excitons



Excitons

Density Functional Theory



Conduction

Band gap is wrong

Valence

Effective single particle systems

$$\left(-\frac{1}{2}\nabla^2 + V_{Ext} + V_H + V_{XC} \right) \Phi_i = E_i \Phi_i$$

Independent Particle Approximation

$$\text{Im}(\epsilon_M(\omega)) \sim \lim_{q \rightarrow 0} \sum_{cvk} \left| \langle ck | p | vk \rangle \right|^2 \delta(E(c) - E(v) - \hbar\omega)$$

GW calculations

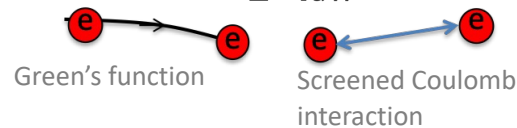


Corrected band gap

Correct e-e interaction

$$\left(-\frac{1}{2}\nabla^2 + V_{Ext} + V_H + \boxed{V_{XC}} \right) \Phi_i = E_i \Phi_i$$

$$\Sigma = iGW$$



BSE calculations



Excitons

Exchange

$$H_{BSE} = \underbrace{(E(c) - E(v))}_{\text{GW corrected}} \delta_{vv} \delta_{cc} \delta_{kk} + \underbrace{(2V - W)}_{\text{Correlation}}$$

$$H_{BSE} A_{cvk}^S = \Omega^S A_{cvk}^S$$

Exciton level

$$\text{Im}(\epsilon_M(\omega)) \sim \lim_{q \rightarrow 0} \sum_S \left| \sum_{cvk} A_{cvk}^S \langle ck | p | vk \rangle \right|^2 \delta(\Omega^S - \hbar\omega)$$

Excitons

SCIENCE ADVANCES | RESEARCH ARTICLE

CONDENSED MATTER PHYSICS

Giant enhancement of exciton diffusivity in two-dimensional semiconductors

Yiling Yu¹, Yifei Yu¹, Guoqing Li¹, Alexander A. Piretzky², David B. Geohegan², Linyou Cao^{1,3,4,*}

nature nanotechnology

Article

Excitons in mesoscopically reconstructed moiré heterostructures

ACS NANO

Cite This: ACS Nano 2019, 13, 3500–3511

www.acsnano.org

Coherence and Density Dynamics of Excitons in a Single-Layer MoS₂ Reaching the Homogeneous Limit

ARTICLES

<https://doi.org/10.1038/s41565-021-00916-1>

Electrical tuning of optically active interlayer excitons in bilayer MoS₂

NANO LETTERS

pubs.acs.org/NanoLett

Probing the Nature of Single-Photon Emitters in a WSe₂ Monolayer by Magneto-Photoluminescence Spectroscopy

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Letter

nature nanotechnology

LETTERS

<https://doi.org/10.1038/s41565-020-0750-1>

Check for updates

Giant Stark splitting of an exciton in bilayer MoS₂

NANO LETTERS

pubs.acs.org/NanoLett

Temperature-Dependent Excitonic Light Manipulation with Atomically Thin Optical Elements

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Letter

nature nanotechnology

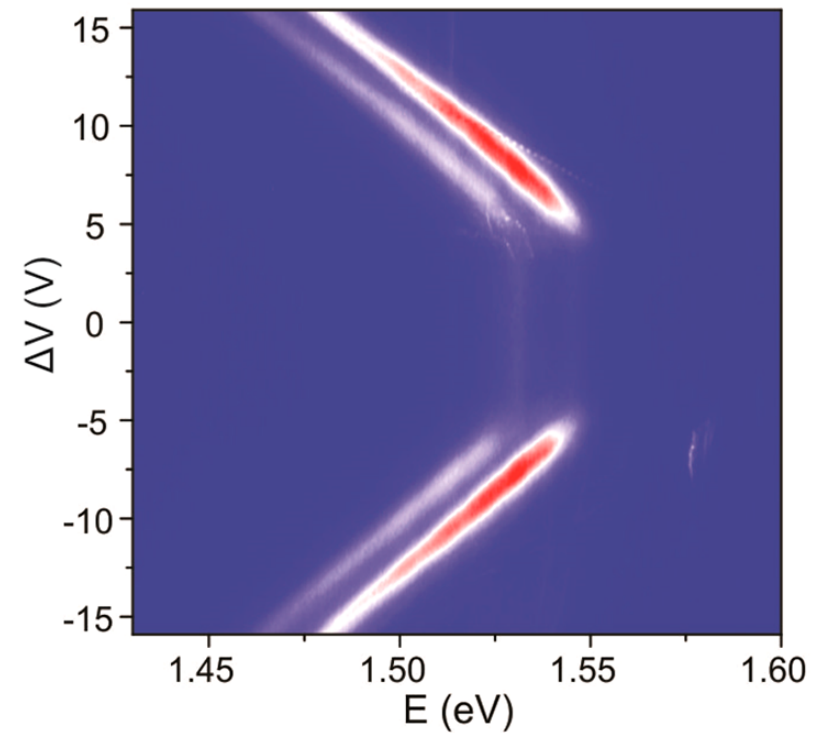
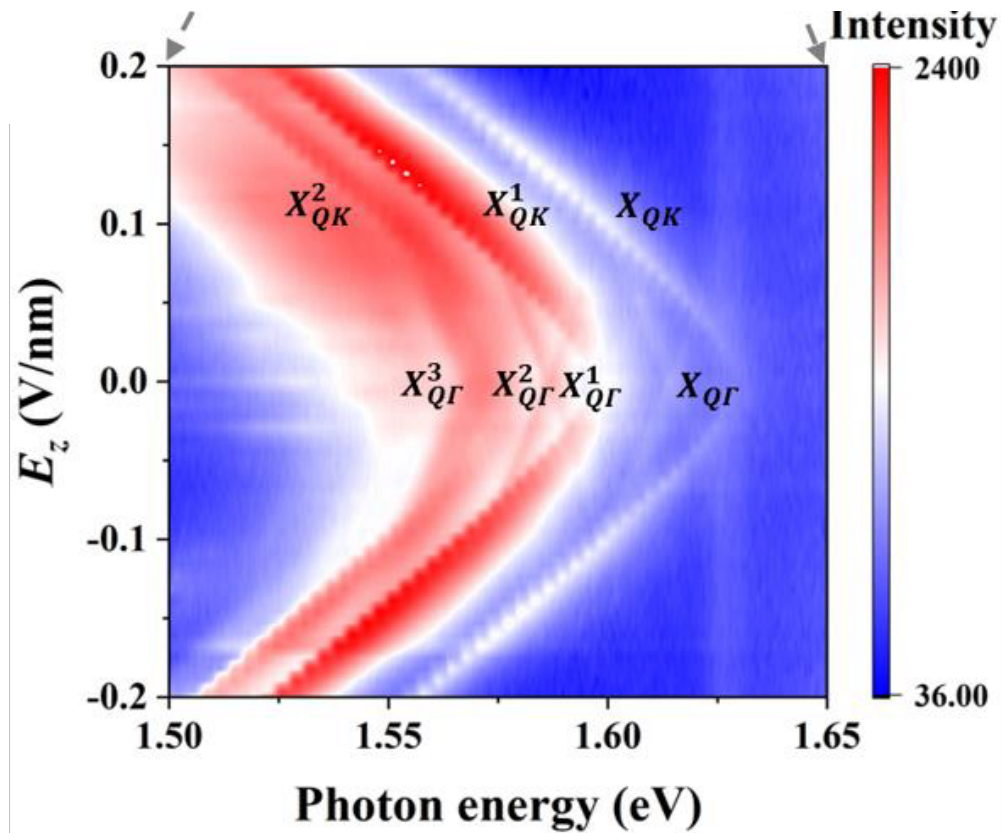
Article

<https://doi.org/10.1038/s41565-023-01438-8>

Ultrafast exciton fluid flow in an atomically thin MoS₂ semiconductor

Lars Hedin

Excitons



Huang et al. Phys. Rev. B 105 (2022) L041419

Yeh et al. Phys. Rev. B 91 (2015) 041407

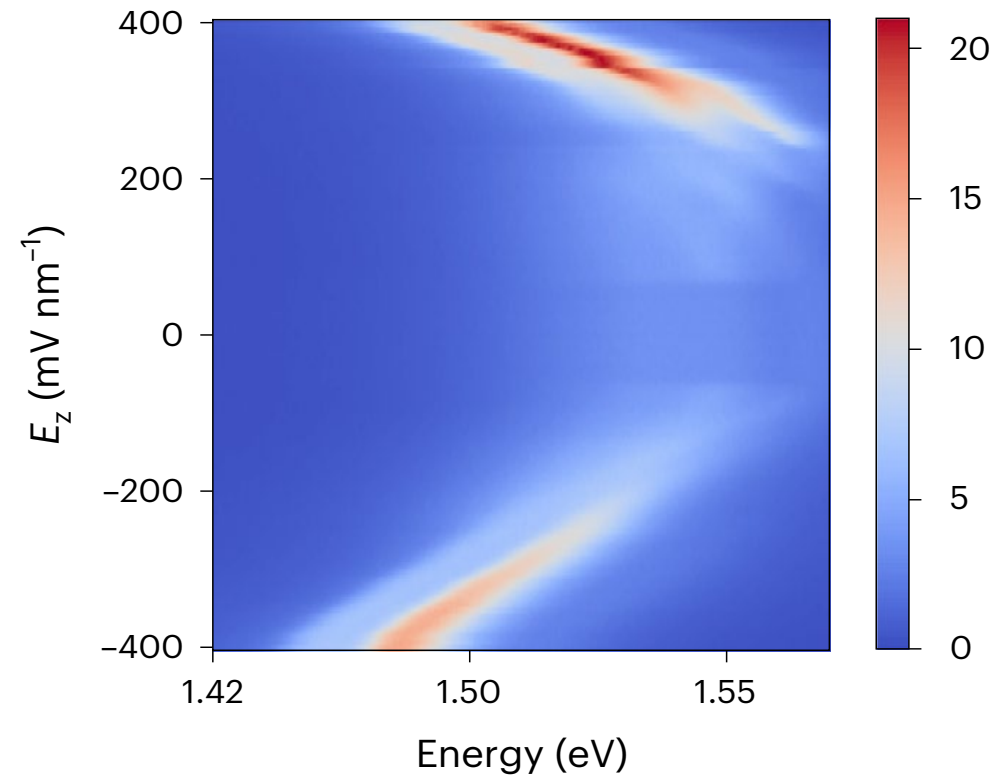
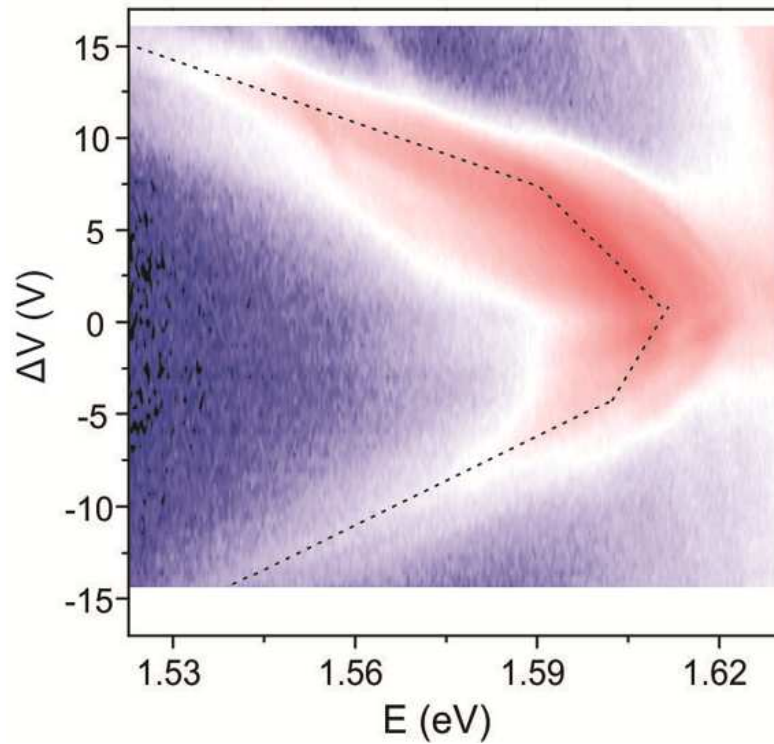
Park et al. 2D Mater. 5 (2018) 025003

Wilson et al. Sci. Adv. 3 (2017) e1601832

Nano Lett. 2018, 18, 1, 137–143

Nature Photonics volume 17, pages 615–621 (2023).

Excitons



Huang et al. Phys. Rev. B 105 (2022) L041419

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Park et al. 2D Mater. 5 (2018) 025003

Wilson et al. Sci. Adv. 3 (2017) e1601832

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Independent Particle Approximation

$$\text{Im}(\epsilon_M(\omega)) \sim \lim_{q \rightarrow 0} \sum_{cvk} \left| \langle ck | p | vk \rangle \right|^2 \delta(E(c) - E(v) - \hbar\omega)$$

22 Different Cases

20 h/case in 2 Tier-1 nodes

GW calculations



Corrected band gap

Correct e-e interaction

$$\left(-\frac{1}{2}\nabla^2 + V_{Ext} + V_H + \boxed{V_{XC}}\right)\Phi_i = E_i\Phi_i$$

$$\Sigma = iGW$$



Green's function



Screened Coulomb interaction

22 Different Cases

48 h/case in 6 Tier-1 nodes

22 Different Cases

12 h/case in 1 Tier-1 nodes Post Processing

BSE calculations



Excitons

Exchange

$$H_{BSE} = \underbrace{(E(c) - E(v))}_{\text{GW corrected}} \delta_{vv} \delta_{cc} \delta_{kk} + \underbrace{(2V - W)}_{\text{Correlation}}$$

$$H_{BSE} A_{cvk}^s = \Omega^s A_{cvk}^s$$

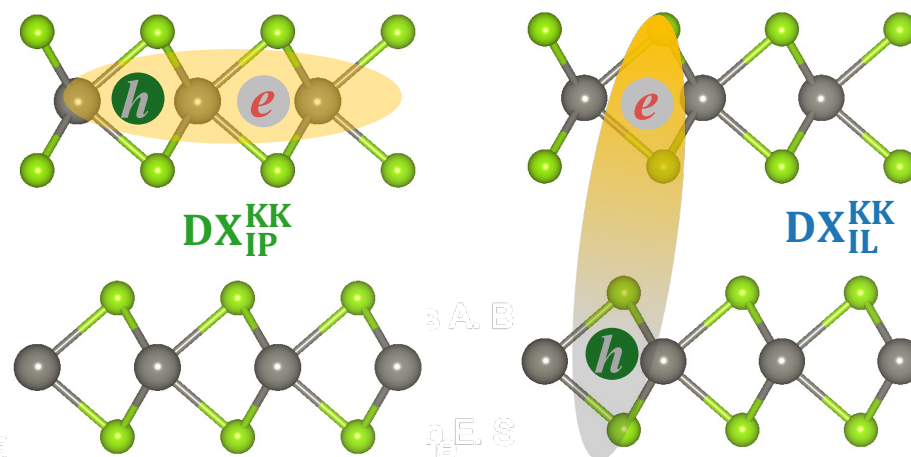
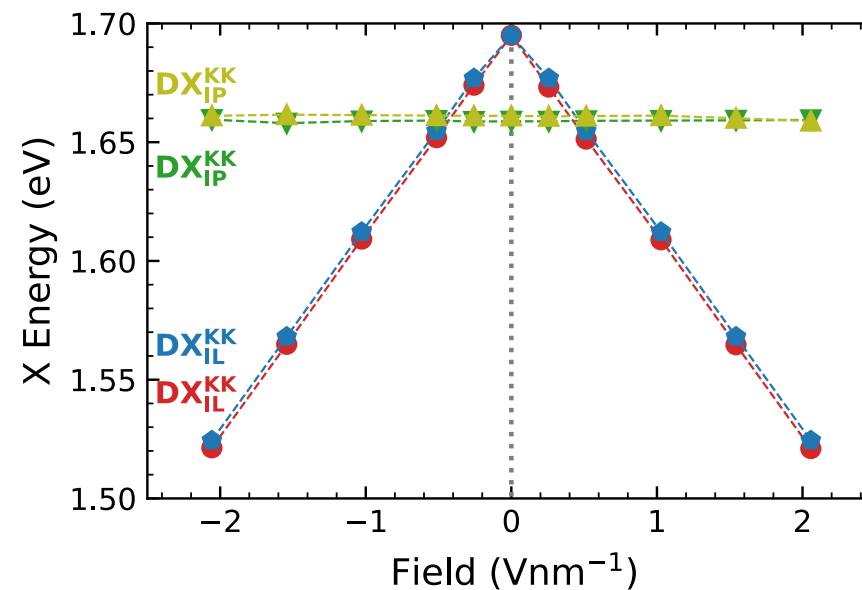
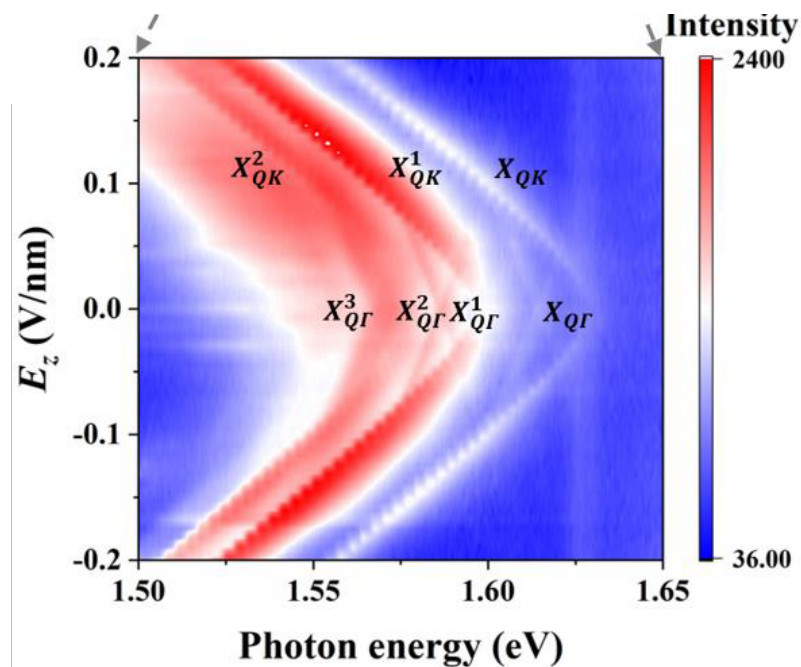
Exciton level

$$\text{Im}(\epsilon_M(\omega)) \sim \lim_{q \rightarrow 0} \sum_S \left| \sum_{cvk} A_{cvk}^s \langle ck | p | vk \rangle \right|^2 \delta(\Omega^s - \hbar\omega)$$

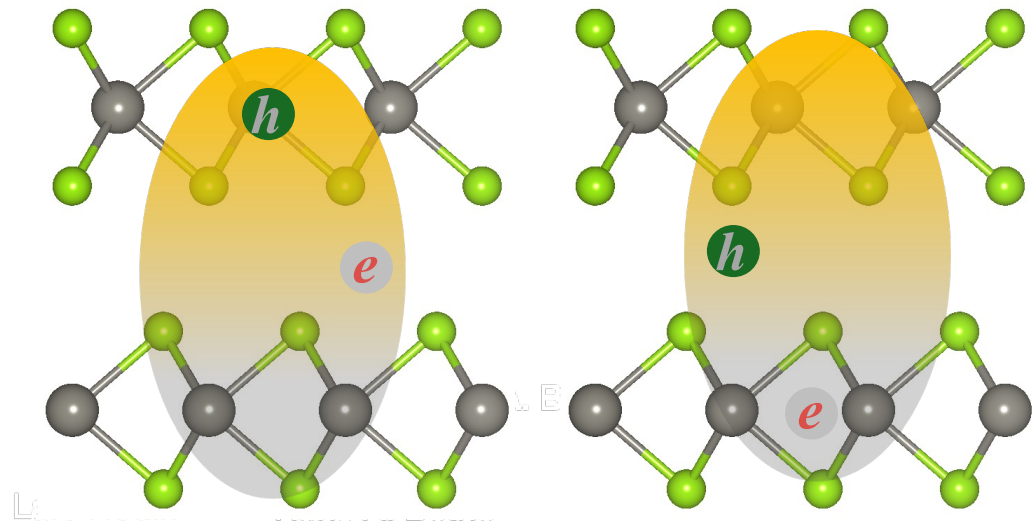
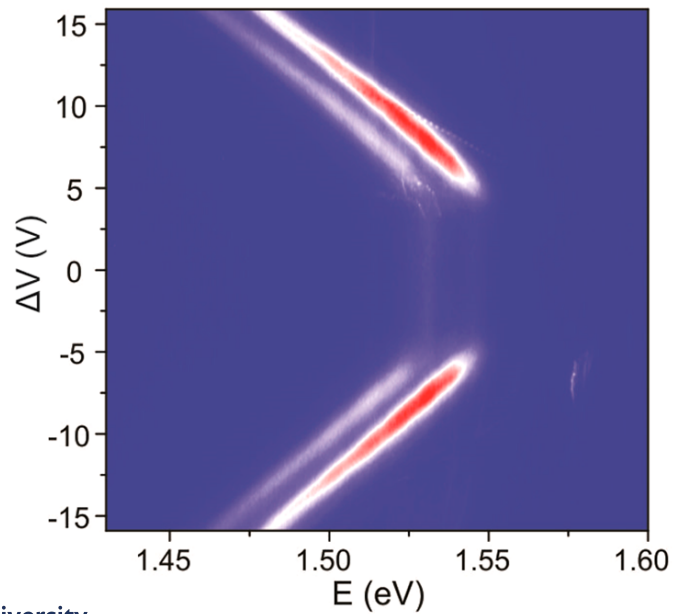
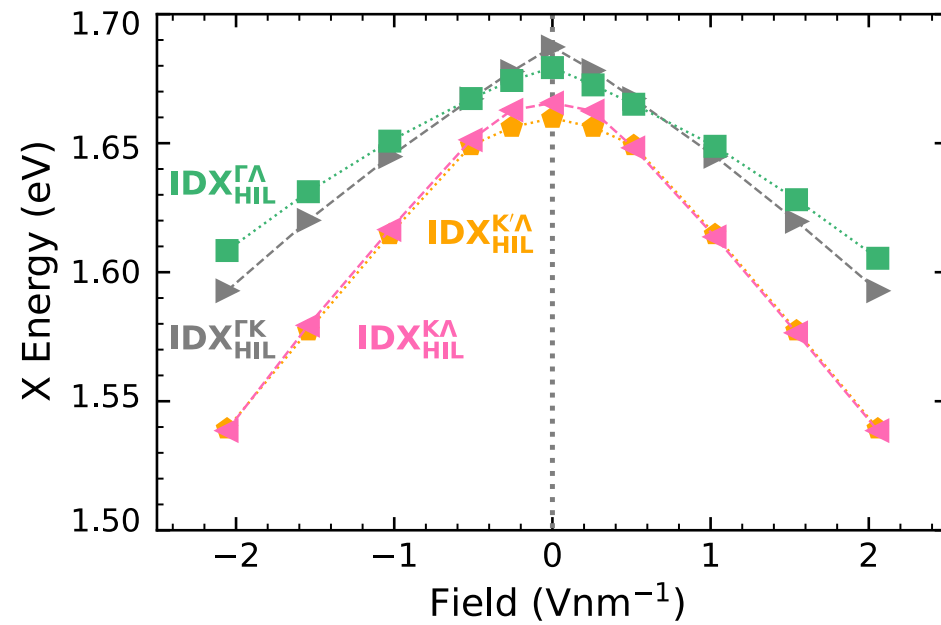
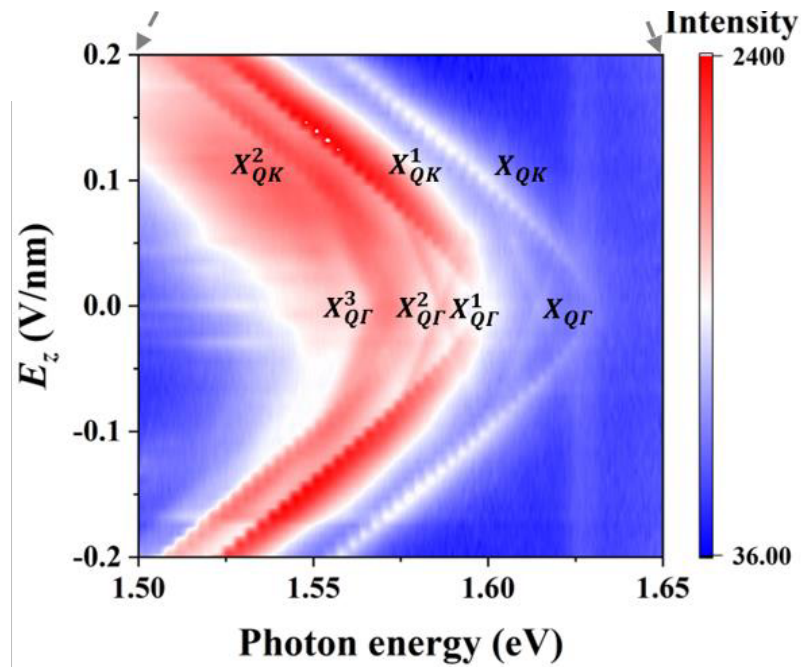
22 Different Cases

24 h/case in 6 Tier-1 nodes

Excitons

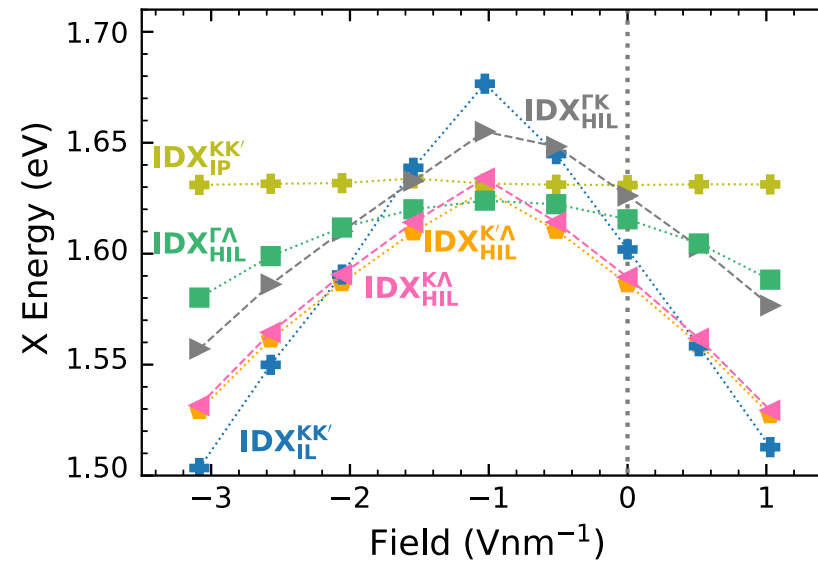
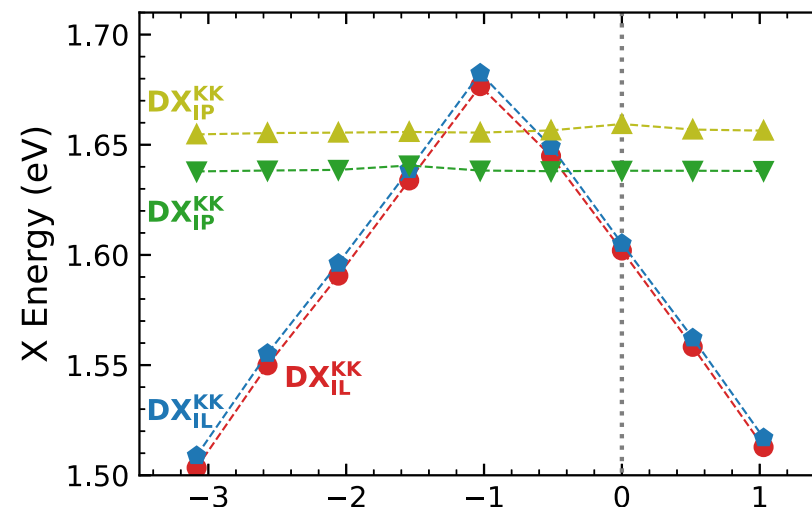
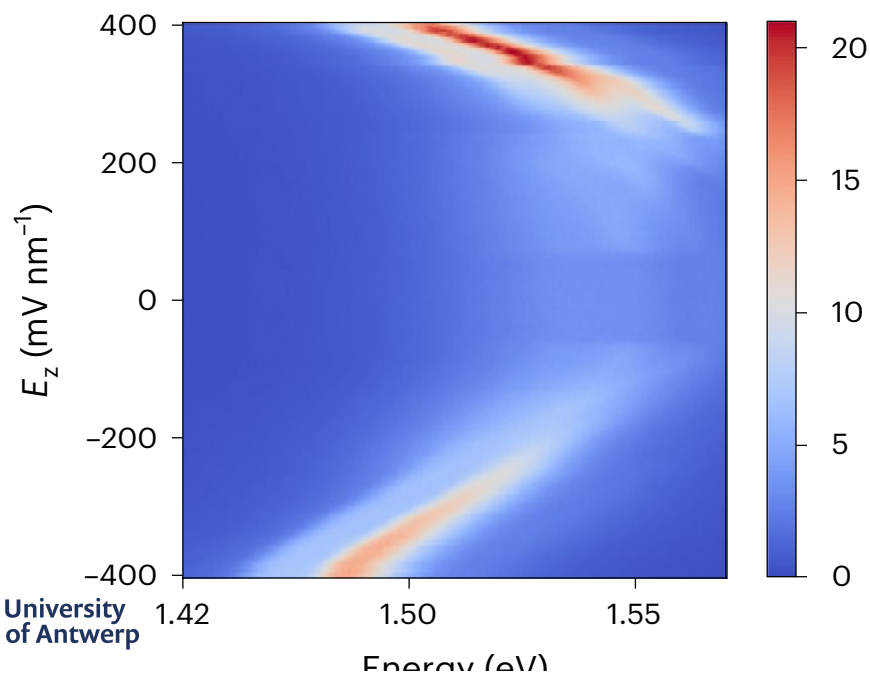
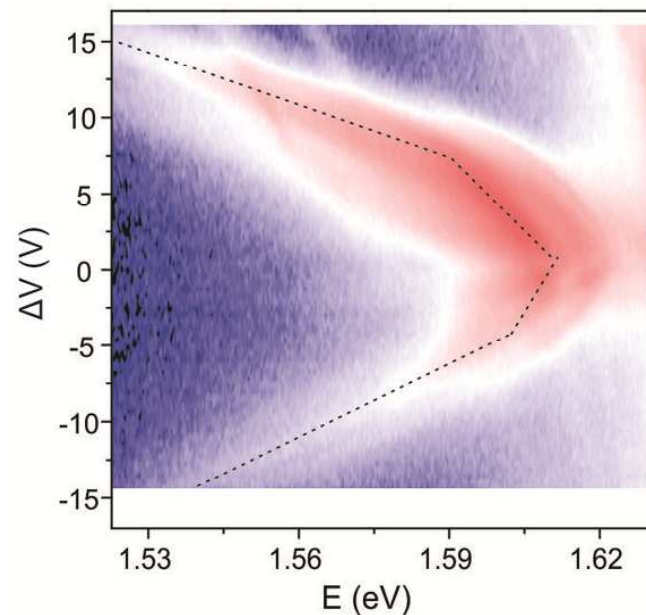


Excitons



Excitons

AB band structure



Lam Hedin

Hans A. Bethe

State- and Momentum-Dependent Nonlinear Stark Effect of Interlayer Excitons in Bilayer WSe₂

Cem Sevik,^{*} Engin Torun, Milorad V. Milošević, and Fulvio Paleari^{*}



Cite This: <https://doi.org/10.1021/acs.nanolett.5c00682>



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Intrinsic Control of Interlayer Exciton Generation in Van der Waals Materials via Janus Layers

Engin Torun,^{*,†} Fulvio Paleari,^{*,†} Milorad V. Milošević, Ludger Wirtz, and Cem Sevik^{*}



Cite This: *Nano Lett.* 2023, 23, 3159–3166



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Optical properties of metallic MXene multilayers through advanced first-principles calculations

Zafer Kandemir^①, Pino D'Amico^②, Giacomo Sesti^②, Claudia Cardoso^{②,*}, Milorad V. Milošević^{③,4} and Cem Sevik^{③,†}

¹Faculty of Engineering and Natural Sciences, *Sabanci University*, 34956 Istanbul, Turkey

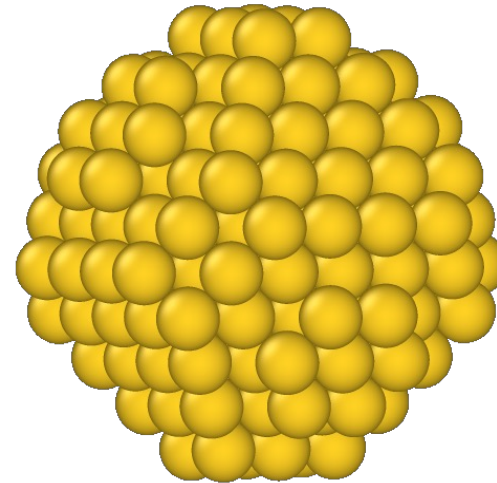
²CNR-NANO Research Center S3, Via Campi 213/a, 41125 Modena, Italy

³Department of Physics and NANOLight Center of Excellence, *University of Antwerp*, Groenenborgerlaan 171, B-2020 Antwerp, Belgium

⁴Instituto de Física, Universidade Federal de Mato Grosso, Cuiabá, Mato Grosso 78060-900, Brazil

Why we need HPC power

Machine Learning Interatomic Potentials for Materials



VLAAMS
SUPERCOMPUTER
CENTRUM

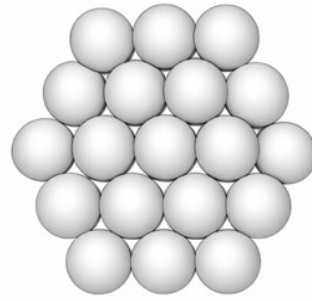
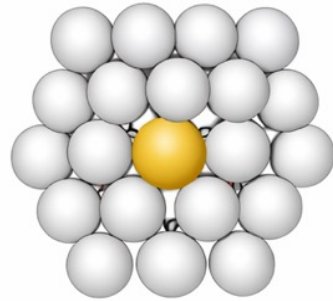


Vlaanderen
is supercomputing

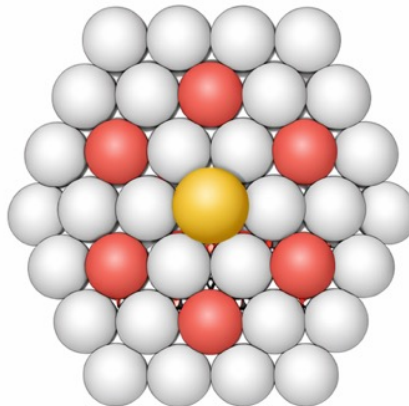
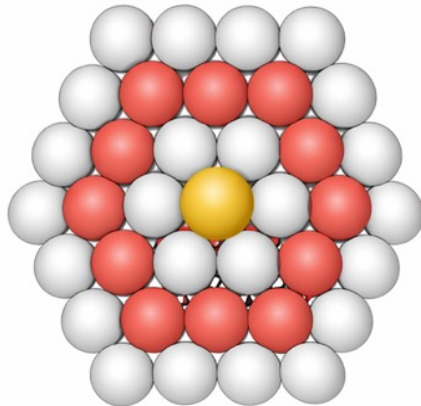


L U M I

ML Interatomic Potentials



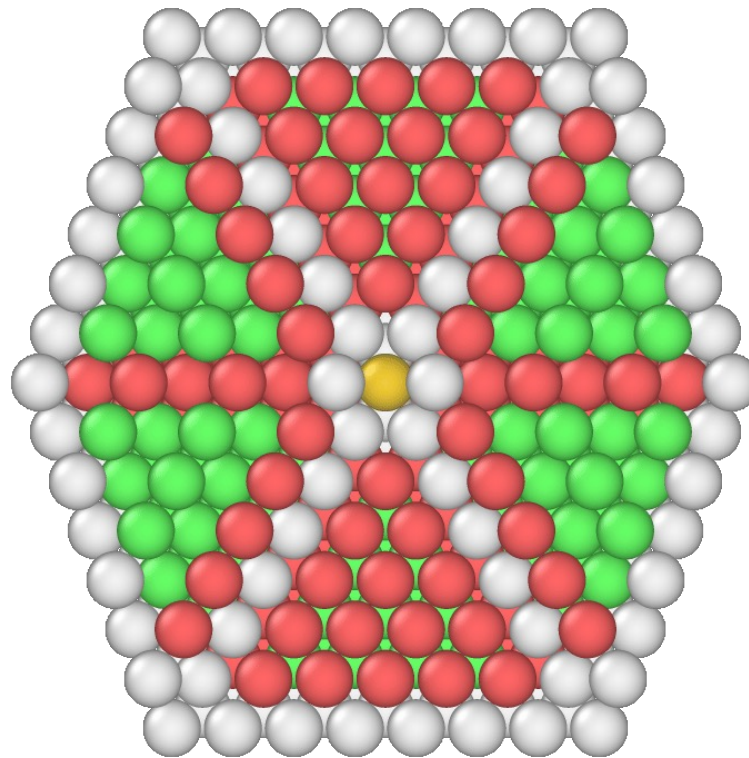
~ 60 Atoms



~ 150 Atoms

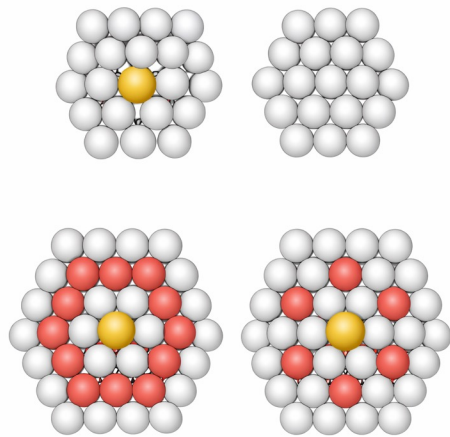
ML Interatomic Potentials

~ 1600 Atoms

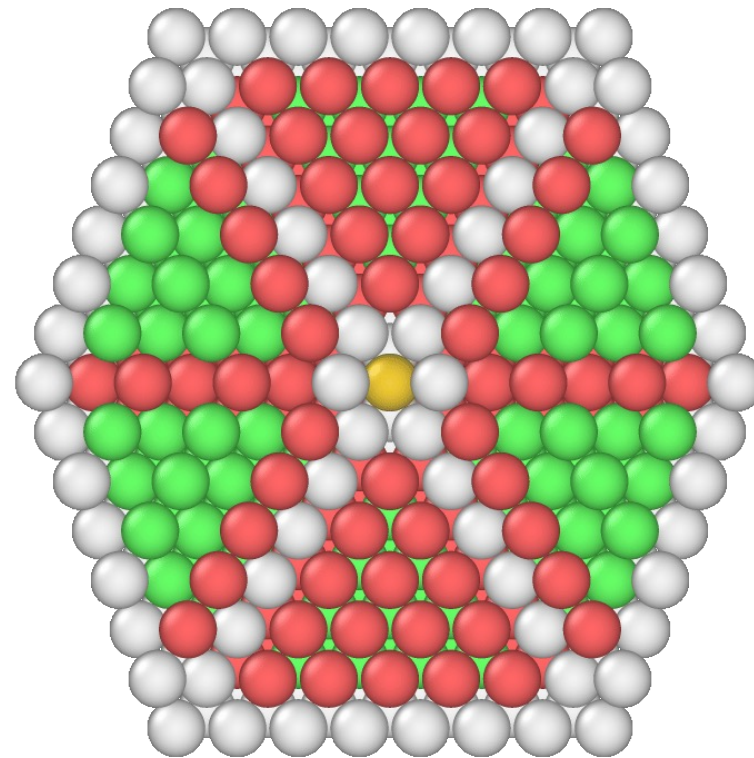


ML Interatomic Potentials

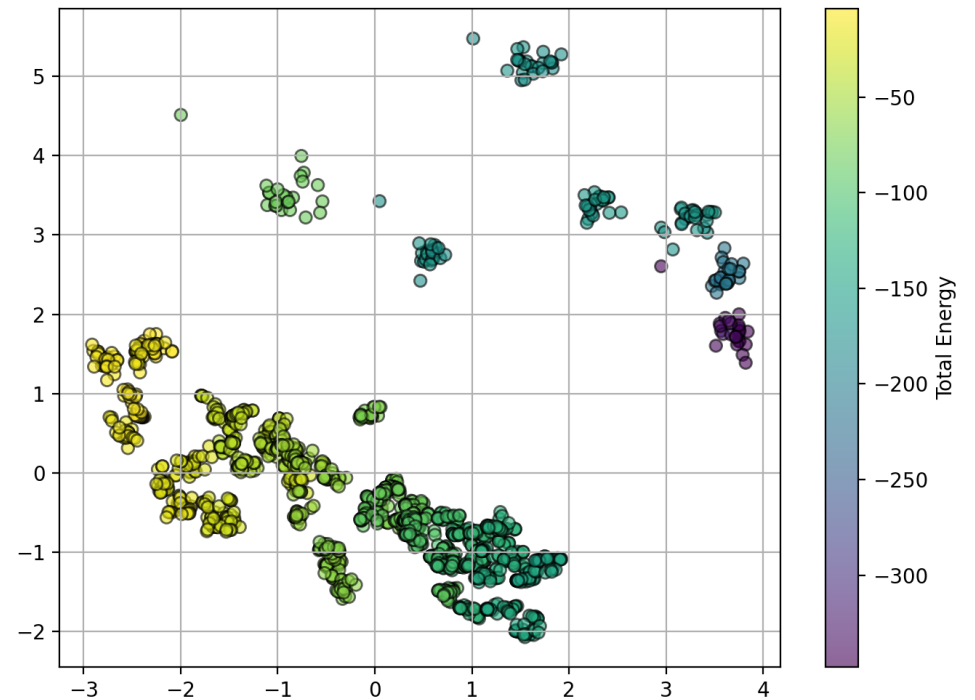
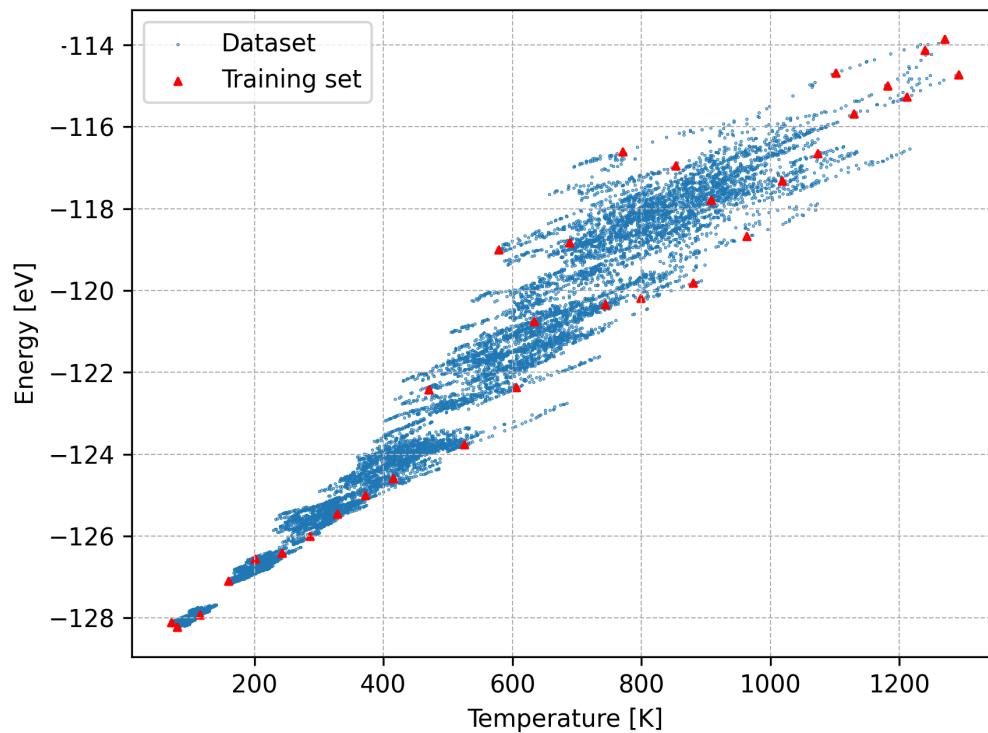
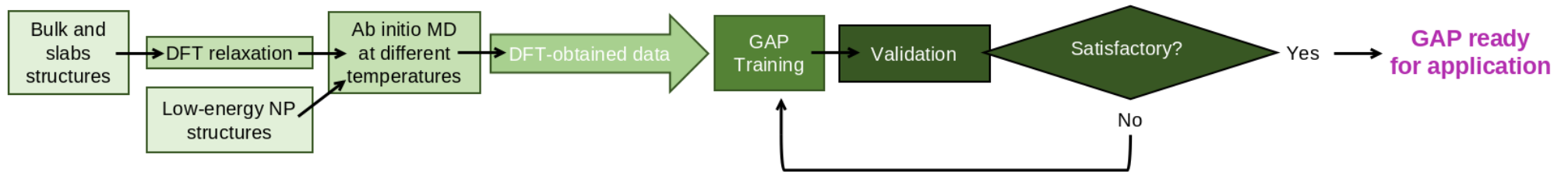
Train ML
Potential



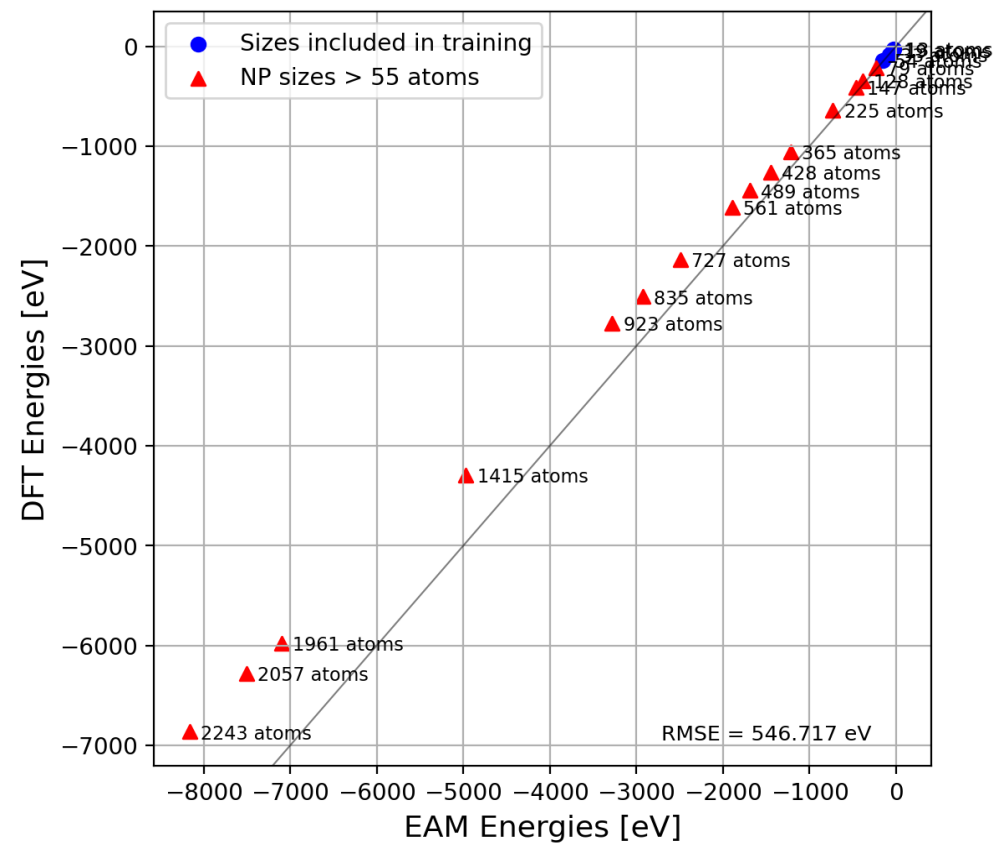
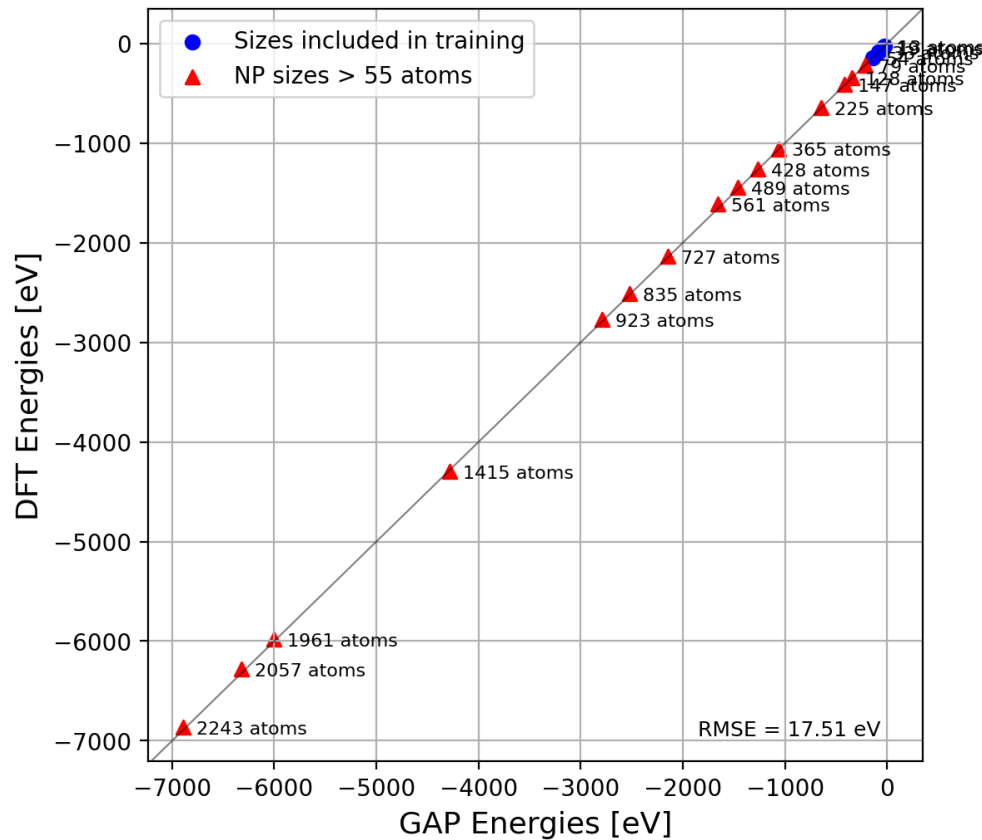
Solve Large
Particles



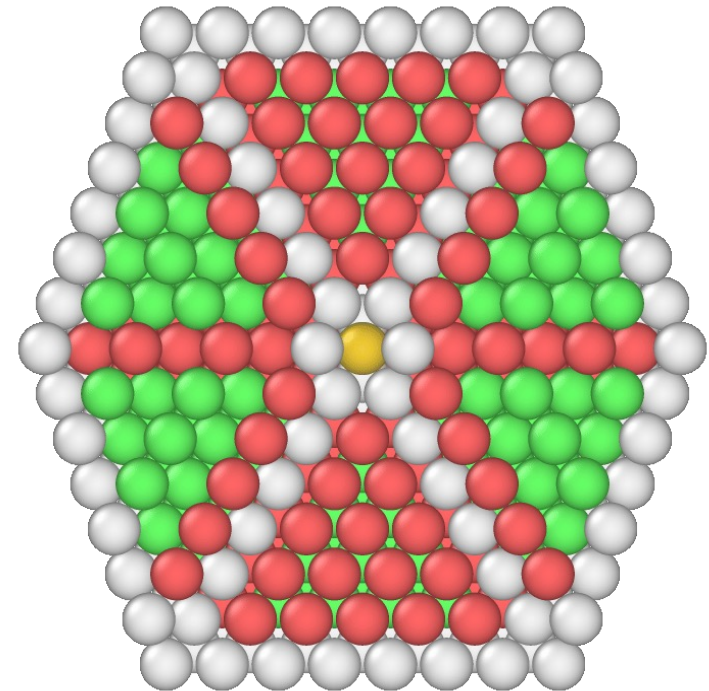
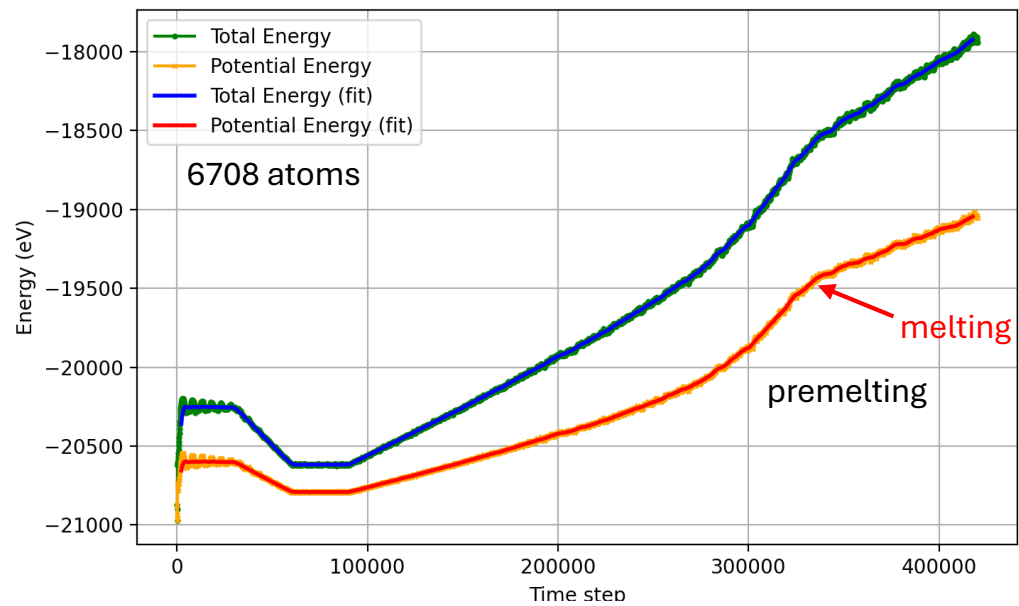
ML Interatomic Potentials



ML Interatomic Potentials



ML Interatomic Potentials

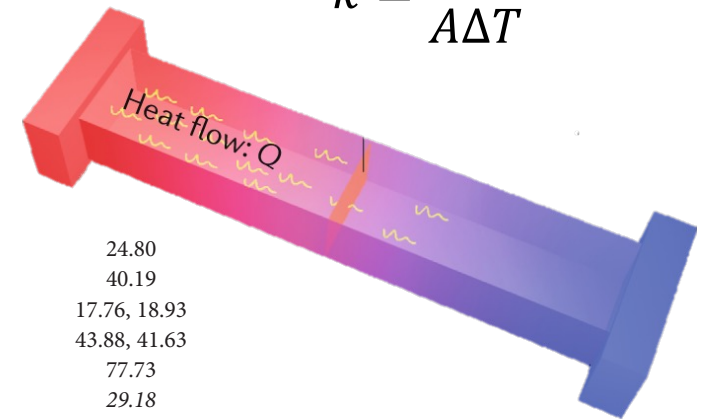


ML Interatomic Potentials

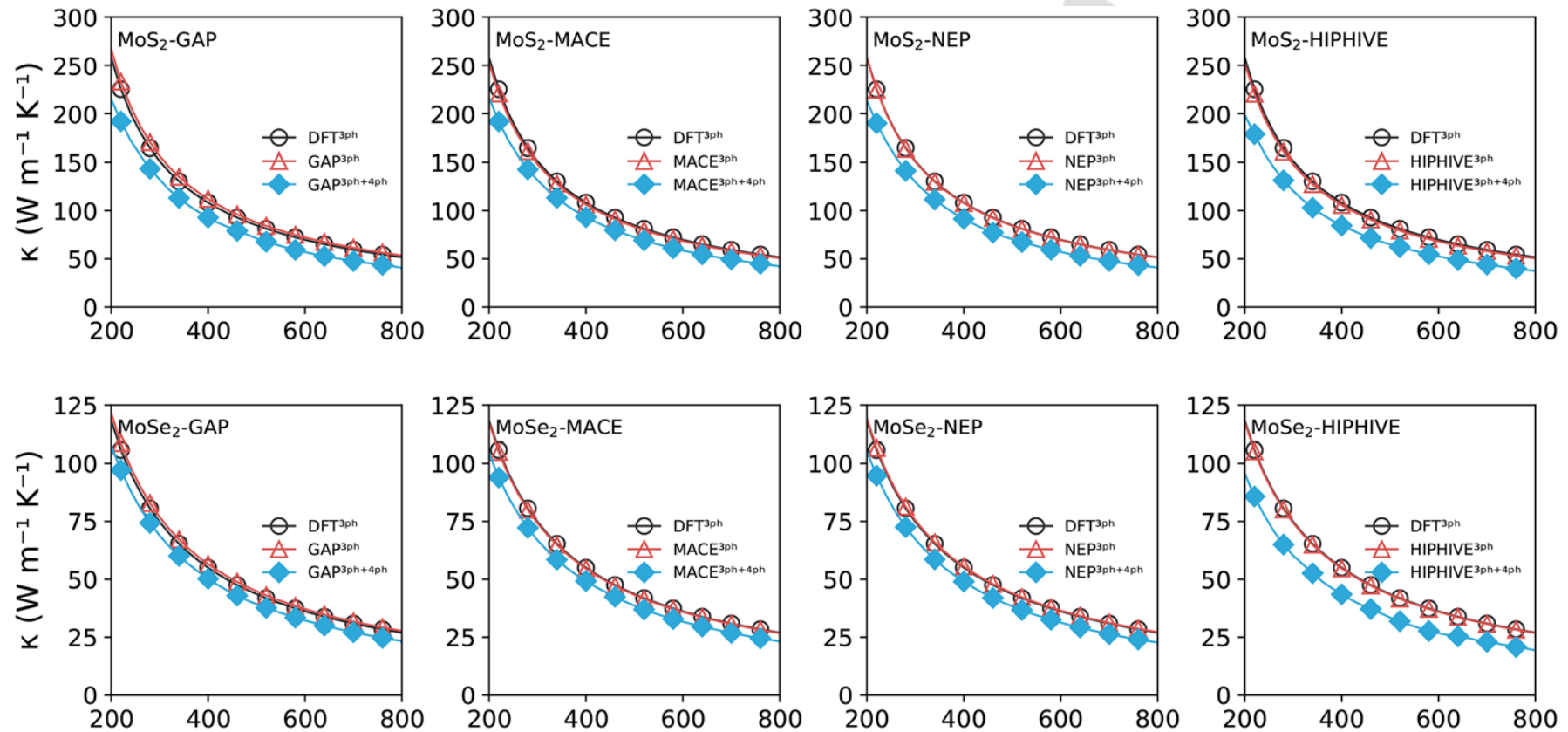
TABLE I. Room-temperature lattice thermal conductivity values of monolayer MoS₂ and MoSe₂ collected from the literature, based on first-principles, molecular dynamics, and experimental studies. All reported values have been rescaled according to the out-of-plane lattice constants used in this work: 6.15 Å for MoS₂ and 6.47 Å for MoSe₂. Italicized values indicate that the original source did not provide an explicit out-of-plane lattice constant.

First-principles			
MoS ₂		MoSe ₂	
Method	κ (Wm ⁻¹ K ⁻¹)	Method	κ (Wm ⁻¹ K ⁻¹)
DFT-BTE ⁵⁸	151.36	DFT-BTE ⁵⁹	54.13
DFT-BTE ⁶⁰	135.20	DFT-BTE ⁶¹	~ 70
DFT-BTE ⁶²	130.20	DFT-BTE ⁶³	~ 60
DFT-BTE ⁶⁴	130.00	DFT-BTE ⁶⁵	54
DFT-BTE ⁶⁵	103.00	DFT-BTE ⁶⁶	46.2
DFT-BTE ⁶⁷	81.42	DFT-DFPT-Slack Model ⁶⁸	17.6
DFT-BTE ⁵⁹	89.56		
DFT-DFPT-NEGF ⁶⁹	24.52		
DFT-BTE (3 ^{ph} , 3 ^{ph} +4 ^{ph}) ⁷⁰	133.5, 27.7		
DFT-BTE ⁶⁶	82.2		
DFT-BTE ⁶³	~ 75		
DFT-DFPT-Slack Model ⁶⁸	33.6		
DFT-DFPT-Umklapp Model ⁷¹	29.2		
<i>Molecular Dynamics</i>			
REBO-LJ-HNEMD ²⁴	123.66	SW-NEMD ²⁵	24.80
(SW13, SW13E, SW16)-HNEMD ²⁴	535.85, 203.98, 290.65	SW-EMD-Green-Kubo ¹⁹	40.19
TB-(EMD-NEMD) ²⁰	0.97, 1.22	SW-NEMD-(AC, ZZ) ²¹	17.76, 18.93
SW-NEMD ²⁵	32.89	SW-NEMD-(AC, ZZ) ¹⁶	43.88, 41.63
SW-RNEMD-(AC, ZZ) ²³	32.95, 53.91	MLFF-NEP-HNEMD ¹⁷	77.73
SW-EMD-Green-Kubo ¹⁹	90.00	SW-SED ²²	29.18
SW-EMD-Green-Kubo ¹⁸	116.99		
SW-NEMD-(AC, ZZ) ¹⁶	101.39, 110.26		
SW-NEMD ¹⁵	19.95		
MLFF-NEP-HNEMD ¹⁷	161.62		
SW-SED ²²	89.4		
<i>Experimental</i>			
Raman (Heat Diff. Modeling) ³	36.46	Mech.Exf.-Raman (vacuum, air) ¹⁰	(20, 250)
Raman (Heat Diff. Modeling) ⁷²	70.80	Mech.Exf.-Raman ⁶	59
CVD-RTD ⁷³	30		
Mech.Exf.-Raman ⁶	84		
CVD-Opt. Mod. ⁷⁴	19.8		
CVD-LHD ⁶⁰	13.3		
CVD-MJH ¹²	24–100		

$$\kappa = \frac{\Delta Q}{A\Delta T}$$



ML Interatomic Potentials



ML Interatomic Potentials

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Gaussian approximation potentials for accurate thermal properties of two-dimensional materials†

Cite this: *Nanoscale*, 2023, **15**, 8772

Tuğbey Kocabaş, ^{*a} Murat Keçeli, ^{*b} Álvaro Vázquez-Mayagoitia ^{*b} and Cem Sevik ^{*c,d}

Thermal conductivity limits of MoS₂ and MoSe₂: Revisiting high-order anharmonic lattice dynamics with machine learning potentials

Cite as: *Appl. Phys. Rev.* **12**, 000000 (2025); doi: [10.1063/5.0300627](https://doi.org/10.1063/5.0300627)

Submitted: 3 September 2025 · Accepted: 3 December 2025 ·

Published Online: 0 Month 0000



Tuğbey Kocabaş,¹ ¹ Murat Keçeli,² ² Tanju Gürel,³ ³ Milorad V. Milošević,⁴ ⁴ and Cem Sevik^{4,a)} 

HPC

VLAAMS
SUPERCOMPUTER
CENTRUM



Vlaanderen
is supercomputing

Tier – 1

- PWSCF
- YAMBO
- VASP
- ABINIT

Tier – 2

- PWSCF
- YAMBO
- VASP
- ABINIT
- ML

Ghent (CPU)

Ghent (GPU)



GPU

- PWSCF
- YAMBO
- BSE (Limited)

L U M I

CPU

- PWSCF
- YAMBO

GPU

- PWSCF
- YAMBO
- Screening
- GW

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12 MONTHS



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CPU

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GPU

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- YAMBO

Screening

GW

12 MONTHS

THANK YOU

